




	<h2>SIR404DP-T1-GE3</h2>
	<p>Hersteller-Teilenummer: SIR404DP-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CH 20V 60A PPAK SO-8</p> <p>Datenblätter:  SIR404DP-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 20322 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SIR404DP-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 20V 60A PPAK SO-8
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	20322 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	PowerPAK® SO-8
Supplier Device-Gehäuse	PowerPAK® SO-8
Verlustleistung (max)	6.25W (Ta), 104W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	60A (Tc)
Rds On (Max) @ Id, Vgs	1.6 mOhm @ 20A, 10V
VGS (th) (Max) @ Id	1.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	97nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	8130pF @ 10V
Antriebsspannung (Max Rds On, Min Rds On)	2.5V, 10V
Vgs (Max)	±12V
Verpackung	Tape & Reel (TR)



















































SIR404DP-T1-GE3 ist neu im Original, Suche SIR404DP-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SIR404DP-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SIR404DP-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SIR404DP VB SIR404DP VB</p>	 <p>SIR402DP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 35A PPAK SO-8</p>	 <p>SIR406DP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 25V 40A PPAK SO-8</p>	 <p>SIR404DP-T1-E3 VISHAY SIR404DP-T1-E3 VISHAY</p>
 <p>SIR406DP SI SIR406DP SI</p>	 <p>SIR406DP-T1-GE3 Vishay / Siliconix MOSFET N-CH 25V 40A PPAK SO-8</p>	 <p>SIR403EDP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 30V 40A PPAK 8SO</p>	 <p>SIR404DP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 20V 60A PPAK SO-8</p>

heiße Teile

Mehr

 SIR164DP-T1-E3	 SIR164DP-T1-GE3	 SIR164DP-T1-GE3	 SIR166DP	 SIR166DP-T1-E3
 SIR166DP-T1-GE3	 SIR166DP-T1-GE3	 SIR168DP	 SIR168DP-T1-GE3	 SIR168DP-T1-GE3
 SIR172ADP-T1-GE3	 SIR172ADP-T1-GE3	 SIR172DP	 SIR172DP-T1-E3	 SIR172DP-T1-GE3
 SIR172DP-T1-GE3	 SIR330DP-T1-GE3	 SIR330DP-T1-GE3	 SIR402DP-T1-GE3	 SIR402DP-T1-GE3
 SIR403EDP-T1-GE3	 SIR403EDP-T1-GE3	 SIR404DP	 SIR404DP-T1-E3	 SIR404DP-T1-GE3
 SIR406DP	 SIR406DP-T1-E3	 SIR406DP-T1-GE3	 SIR406DP-T1-GE3	 SIR406DP-T1-GE3-S
 SIR408DP-T1-GE3	 SIR408DP-T1-GE3	 SIR410DP-T1-E3	 SIR410DP-T1-GE3	 SIR410DP-T1-GE3
 SIR412DP	 SIR412DP-T1-E3	 SIR412DP-T1-GE3	 SIR412DP-T1-GE3	 SIR414DP
 SIR414DP-T1-GE3	 SIR414DP-T1-GE3	 SIR416DP	 SIR416DP-T1-E3	 SIR416DP-T1-GE3
 SIR416DP-T1-GE3	 SIR418DP-T1-E3	 SIR418DP-T1-GE3	 SIR418DP-T1-GE3	 SIR422DP-T1-E3

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